

3.3V CMOS 16-BIT REGISTER (3-STATE)

IDT74FCT163374A/C

FFATURFS:

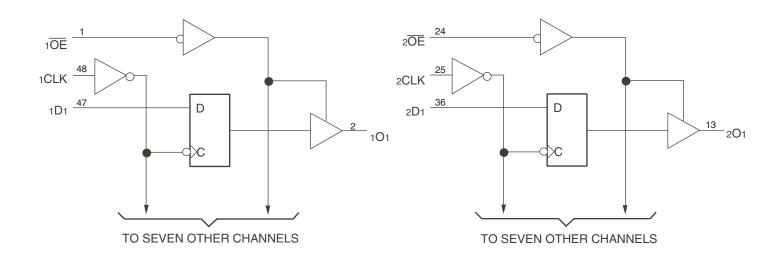
- · 0.5 MICRON CMOS Technology
- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- $Vcc = 3.3V \pm 0.3V$, Normal Range, or Vcc = 2.7V to 3.6V, Extended
- CMOS power levels (0.4 w typ. static)
- · Rail-to-rail output swing for increased noise margin
- Low Ground Bounce (0.3V typ.)
- Inputs (except I/O) can be driven by 3.3V or 5V components
- · Available in SSOP and TSSOP packages

DESCRIPTION:

The FCT163374 16-bit edge-triggered D-type register is built using advanced dual metal CMOS technology. These high-speed, low-power registers are ideal for use as buffer registers for data synchronization and storage. The Output Enable ($x\overline{OE}$) and clock (xCLK) controls are organized to operate each device as two 8-bit registers or one 16-bit register with common clock. Flow-through organization of signal pins facilitates ease of layout. All inputs are designed with hysteresis for improved noise margin.

The inputs of FCT163374 can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in a mixed 3.3V/ 5V supply system.

FUNCTIONAL BLOCK DIAGRAM



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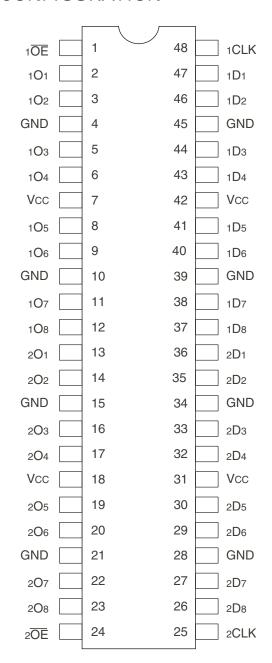
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INDUSTRIAL TEMPERATURE RANGE

MAY 2018

DSC-2775/13

PIN CONFIGURATION



TOP VIEW

Package Type	Package Code	Order Code	
TSSOP	PAG48	PAG	
SSOP	PVG48	PVG	

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	–0.5 to 7	V
VTERM ⁽⁴⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-60 to +60	mA

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. Input terminals.
- 4. Outputs and I/O terminals.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	3.5	6	pF
Соит	Output Capacitance	Vout = 0V	3.5	8	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description		
хDх	Data Inputs		
xCLK	Clock Inputs		
хОх	3-State Outputs		
хŌЕ	3-State Output Enable Input (Active LOW)		

FUNCTION TABLE(1)

		Outputs		
Function	хDх	xCLK	хŌЕ	хОх
Hi-Z	Х	L	Н	Z
	Х	Н	Н	Z
Load Register	L	1	L	L
	Н	1	L	Н
	L	1	Н	Z
	Н	1	Н	Z

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - X = Don't Care
 - Z = High-Impedance
 - ↑ = LOW-to-HIGH transition

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, VCC = 2.7V to 3.6V

Symbol	Parameter	Test Condi	tions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
ViH	Input HIGH Level (Input pins)	Guaranteed Logic HIGH Level		2	_	5.5	V
	Input HIGH Level (I/O pins)			2	_	Vcc+0.5	
VIL	Input LOW Level (Input and I/O pins)	Guaranteed Logic LOW Level		-0.5	_	0.8	V
Іін	Input HIGH Current (Input pins)	Vcc = Max.	VI = 5.5V	_	_	±1	
	Input HIGH Current (I/O pins)		VI = VCC	_	_	±1	μΑ
lıL	Input LOW Current (Input pins)		VI = GND	_	_	±1	
	Input LOW Current (I/O pins)		VI = GND	_	_	±1	
Іоzн	High Impedance Output Current	Vcc = Max.	Vo = Vcc	_	_	±1	μA
lozL	(3-State Output pins)		Vo = GND	<u> </u>	_	±1	
Vik	Clamp Diode Voltage	VCC = Min., IIN = -18mA		_	-0.7	-1.2	V
lodн	Output HIGH Current	VCC = 3.3V, VIN = VIH or VIL, VO = 1.5V ⁽³⁾		-36	-60	-110	mA
lodl	Output LOW Current	VCC = 3.3V, VIN = VIH or VIL, VO =	1.5V ⁽³⁾	50	90	200	mA
Vон	Output HIGH Voltage	Vcc = Min.	Iон = -0.1mA	Vcc-0.2	_	_	
		VIN = VIH or VIL	Iон = -3mA	2.4	3	_	V
		VCC = 3V	Іон = –8mА	2.4(5)	3	_	
		VIN = VIH or VIL					
Vol	Output LOW Voltage	Vcc = Min.	IOL = 0.1mA		_	0.2	
		VIN = VIH or VIL	IOL = 16mA	_	0.2	0.4	
			IOL = 24mA	_	0.3	0.55	V
		VCC = 3V	IOL = 24mA	_	0.3	0.5	
		VIN = VIH or VIL					
los	Short Circuit Current ⁽⁴⁾	Vcc = Max., Vo = GND ⁽³⁾		-60	-135	-240	mA
VH	Input Hysteresis	_		_	150	_	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = Max. Vin = GND or Vcc			0.1	10	μΑ

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. This parameter is guaranteed but not tested.
- 5. Voh = Vcc-0.6V at rated current.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions	S ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
∆lcc	Quiescent Power Supply Current TTL Inputs HIGH	$VCC = Max.$ $VIN = VCC - 0.6V^{(3)}$		_	2	30	μΑ
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open xOE = GND One Input Toggling 50% Duty Cycle	VIN = VCC VIN = GND	_	50	75	μΑ/ MHz
Ic	fcP = 10MHz 50% Duty Cycle xOE = GND fi = 5MHz One Bit Toggling Vcc = Max., Outputs Open fcP = 10MHz 50% Duty Cycle	fcp = 10MHz 50% Duty Cycle	VIN = VCC VIN = GND	_	0.5	0.8	mA
		fi = 5MHz	VIN = VCC -0.6V VIN = GND	_	0.5	0.8	
		VIN = VCC VIN = GND	_	2.5	3.8 ⁽⁵⁾		
		$x\overline{OE} = \overline{GND}$ fi = 2.5MHz	VIN = VCC -0.6V VIN = GND	_	2.5	4 ⁽⁵⁾	

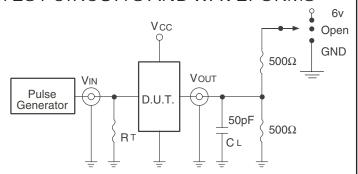
- 1. For conditions shown as max. or min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.
- 3. Per TTL driven input; all other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
 - IC = ICC + DICC DHNT + ICCD (fcpNcp/2 + fiNi)
 - Icc = Quiescent Current (IccL, IccH and Iccz)
 - Δlcc = Power Supply Current for a TTL High Input
 - DH = Duty Cycle for TTL Inputs High
 - NT = Number of TTL Inputs at DH
 - ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
 - fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)
 - NCP = Number of Clock Inputs at fCP
 - f_i = Input Frequency
 - Ni = Number of Inputs at fi

SWITCHING CHARACTERISTICS OVER OPERATING RANGE(1)

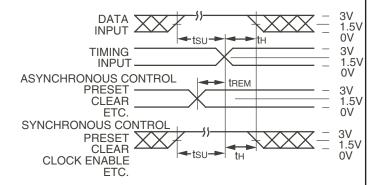
			FCT163374A		FCT163374C		
Symbol	Parameter	Condition ⁽²⁾	Min. ⁽³⁾	Max.	Min. ⁽³⁾	Max.	Unit
tPLH	Propagation Delay	CL = 50pF	2	6.5	2	5.2	ns
tPHL	xCLK to xOx	$RL = 500\Omega$					
tpzh	Output Enable Time]	1.5	6.5	1.5	5.5	ns
tpzl							
tphz	Output Disable Time]	1.5	5.5	1.5	5	ns
tplz							
tsu	Set-up Time HIGH or LOW, xDx to xCLK	1	2	_	2	_	ns
1H	Hold Time HIGH or LOW, xDx to xCLK	1	1.5	_	1.5	_	ns
tw	xCLK Pulse Width HIGH	1	5	_	5	_	ns
tsk(o)	Output Skew ⁽⁴⁾		_	0.5	_	0.5	ns

- 1. Propagation Delays and Enable/Disable times are with Vcc = 3.3V ±0.3V, Normal Range. For Vcc = 2.7V to 3.6V, Extended Range, all Propagation Delays and Enable/Disable times should be degraded by 20%.
- 2. See test circuit and waveforms.
- 3. Minimum limits are guaranteed but not tested.
- 4. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.

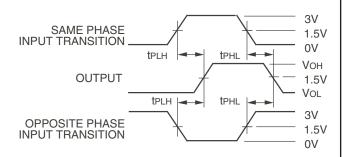
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-up, Hold, and Release Times



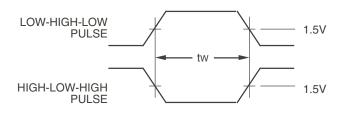
Propagation Delay

SWITCH POSITION

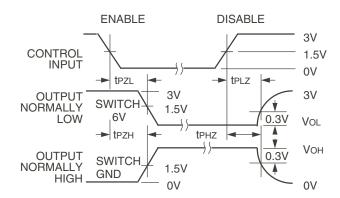
Test	Switch
Open Drain Disable Low Enable Low	6V
Disable High Enable High	GND
All Other Tests	Open

DEFINITIONS:

- CL = Load capacitance: includes jig and probe capacitance.
- RT = Termination resistance: should be equal to ZouT of the Pulse Generator.



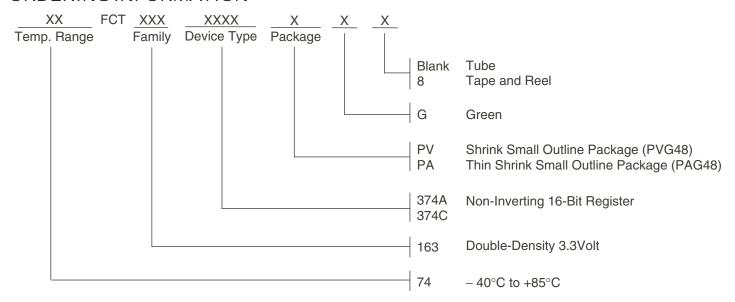
Pulse Width



Enable and Disable Times

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.
- 3. if Vcc is below 3V, input voltage swings should be adjusted not to exceed Vcc.

ORDERING INFORMATION



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
Α	74FCT163374APAG	PAG48	TSSOP	I
	74FCT163374APAG8	PAG48	TSSOP	I
	74FCT163374APVG	PVG48	SSOP	Ι
	74FCT163374APVG8	PVG48	SSOP	I
С	74FCT163374CPAG	PAG48	TSSOP	I
	74FCT163374CPAG8	PAG48	TSSOP	I
	74FCT163374CPVG	PVG48	SSOP	Ī
	74FCT163374CPVG8	PVG48	SSOP	I

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